# **Supplementary Information for**

## Engineering of a genetic circuit with regulatable multistability

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**Fig. S1.** FACS and re-culturing of cell populations in different states for inducible toggle switch. The sub-figure in the Lower left corner is the population distribution before sorting



Fig. S2. Time-course measurement of the ITS after induction by an IPTG concentration gradient.



**Fig. S3.** Comparison of percentage of ON cells between samples before and twelve hours after dilution. Left panel: Triplicate results from the dilution experiment (Fig. 2C and Fig. 2D). Each clone was randomly selected from a separate single colony on an agar plate. All three clones showed similar ON-OFF ratios before dilution and twelve hours after dilution. Right panel: Statistical analysis for the triplicate results. The histogram with error bars indicated mean  $\pm$  SD. P value was calculated from



**Fig. S4.** Control circuit used to prove that the activation of T7 RNAP without positive feedback cannot produce bistability. Lef3t: the design of the control circuit; T7RNAP is expressed from the  $P_{TAC}$  promoter. The T7 RNAP will transcribe the downstream sfGFP from the  $P_{T7M4}$  promoter. Right: gradient induction of the circuit led to gradient and unimodal expression of sfGFP.



**Fig. S5.** Combinatorial genetic circuit exhibited a durable tristable population distribution both before dilution and after another 12 hours of culture after dilution.



**Fig. S6.** Plasmid maps and a representative configuration of their promoter regions: pT7RNAP (a) and sfGFP (b) were used for the self-activation circuit; pITS-repressors (c) and pITS-reporters (d) were used for the inducible toggle switch; pT7RNAP (a) and pITS (e) were used for the combinatorial tristable circuit. The RiboJ insulator is labeled in the map where it was used, RBS/operator/spacer are not shown on the maps in some cases for sake of simplicity. (f) A representative configuration of the bi-directional promoter encoded with operators; RiboJ is not shown completely.



**Fig. S7.** Design of the microfluidics chip used to characterize the induction dynamics of ITS

### Modeling

#### **ITS model**

Our circuit is designed to be a general toggle switch that consist of two proteins A and B with concentrations [A] and [B] respectively, which negatively regulate each other's synthesis. Additionally the synthesis of the two proteins are controlled by the concentration of *RNAP*, donated by [P]. Here the state of gene is represented by O, OP, O<sub>An</sub>, etc. In such way, the set of chemical reactions are

$$\begin{split} &O_A + n_2 B \leftrightarrows O_A B_{n2}; \ O_B + n_1 A \leftrightarrows O_B A_{n1} \\ &O_A + P \leftrightarrows O_A P; \ O_B + P \leftrightarrows O_B P \\ &O_A P \to A; \ O_B P \to B; \end{split}$$

$$O_A + O_A P + O_A B_{n2} = O_{A-T}; \quad O_B + O_B P + O_B A_{n1} = O_{B-T}$$
  
The reactions can be described by the rate equations.  
$$[O_A P] = k_{on-AP}[O_A][P] - k_{off-AP}[O_A P];$$
$$[O_B P] = k_{on-BP}[O_B][P] - k_{off-BP}[O_B P];$$

$$[O_B A_{n1}] = k_{on-A} [O_B] [A]^{n1} - k_{off-A} [O_B A_{n1}];$$

$$[O_A \dot{B}_{n2}] = k_{on-B} [O_A] [B]^{n2} - k_{off-B} [O_A B_{n2}];$$

$$\begin{split} & [\dot{A}] = \delta_A + g_A[O_A P] - d_A[A] - n_1[O_A \dot{A}_{n1}]; \\ & [\dot{B}] = \delta_B + g_B[O_B P] - d_B[A] - n_2[O_B \dot{B}_{n2}]; \end{split}$$

Where  $k_X$  denote the forward and backward rate of each reactions.  $g_X$  is the maximal production rate of protein X.,  $\delta_A$  is the biochemical leakage independent on the specific reactions and  $d_X$  is its degradation rate. For simplicity, we ignore the mRNA level and take the processes of transcription and translation as a single step of synthesis. The protein binding process are much faster than the protein synthesis process that the dynamics of  $[O_A P]$ ,  $[O_B P]$ ,  $[O_A A_{n1}]$  and  $[O_B B_{n2}]$  were treated as equilibrium state. Under this assumption, one can take the time derivatives of  $[O_A P]$ ,  $[O_B P]$ ,  $[O_A A_{n1}]$  and  $[O_B B_{n2}]$  to zero, even if the system is away from steady state. These equations can give the expression of  $[O_A P]$  and  $[O_B P]$ .

$$[O_A P] = \frac{\frac{k_{on-AP}}{k_{off-AP}}[P][O_{A-T}]}{1 + \frac{k_{on-AP}}{k_{off-AP}}[P] + \frac{k_{on-B}}{k_{off-B}}[B]^{n_2}}; \ [O_B P] = \frac{\frac{k_{on-BP}}{k_{off-BP}}[P][O_{B-T}]}{1 + \frac{k_{on-BP}}{k_{off-BP}}[P] + \frac{k_{on-A}}{k_{off-A}}[A]^{n_1}};$$

This brings the rate equations to the standard form:

$$\begin{split} & [\dot{A}] = \delta_A + g_A[O_{A-T}] \frac{\frac{k_{on-AP}}{k_{off-AP}}[P]}{1 + \frac{k_{on-AP}}{k_{off-AP}}[P] + \frac{k_{on-B}}{k_{off-B}}[B]^{n_2}} - d_A[A]; \\ & [\dot{B}] = \delta_B + g_B[O_{B-T}] \frac{\frac{k_{on-BP}}{k_{off-AP}}[P]}{1 + \frac{k_{on-BP}}{k_{off-BP}}[P] + \frac{k_{on-A}}{k_{off-A}}[A]^{n_1}} - d_B[A]; \end{split}$$

Finally, we described the expression of the two repressors in the ITS system using the following equation:

$$\frac{dX_{1}}{dt} = A_{1} \cdot \frac{\frac{RNAP}{K_{RNAP}}}{1 + \frac{RNAP}{K_{RNAP}} + \left(\frac{X_{2}}{K_{2}}\right)^{n_{2}}} + B_{1} - D_{1} \cdot X_{1}$$

$$\frac{dX_{2}}{dt} = A_{2} \cdot \frac{\frac{RNAP}{K_{RNAP}}}{1 + \frac{RNAP}{K_{RNAP}} + \left(\frac{X_{1}}{K_{1}}\right)^{n_{1}}} + B_{2} - D_{2} \cdot X_{2}$$
(S1)

where  $X_1$  and  $X_2$  (nM) represent the concentrations of HKcI and cI, respectively; *RNAP* (nM) and  $K_{RNAP}$  (nM) indicate the concentrations of T7 RNAP and its binding affinity to the promoter sequence;  $A_1$  (nMh-1) and  $A_2$  (nMh<sup>-1</sup>) account for the other elements (RBS, copy number, etc.) that control the protein expression apart from transcription;  $K_1$  (nM) and  $K_2$  (nM) are the binding affinities of the repressors;  $n_1$  and  $n_2$  are hill coefficients of repressor binding;  $B_1$  (nMh<sup>-1</sup>) and  $B_2$  (nMh<sup>-1</sup>) are the basal expression rates; and  $D_1$  and  $D_2$  are the decay rate constants. The first term in each line represents the regulated activity of the repressor, the second term is the basal activity and the third term is the unregulated decay of activity.

#### **CTC model**

We combined the ITS model with the SAC model to construct a combinatorial tristable circuit model.

$$\frac{dy}{dt} = \frac{\delta + \alpha \cdot y}{1 + y} + \beta - \frac{\varphi \cdot y}{1 + \theta \cdot y} - y$$

$$z = c \cdot y$$

$$\frac{dx_1}{dt} = a_1 \cdot \frac{z}{1 + z + x_2^{n_2}} + b_1 - x_1 \quad (S2)$$

$$\frac{dx_2}{dt} = a_2 \cdot \frac{z}{1 + z + x_1^{n_1}} + b_2 - x_2$$

This combinatorial model contains three variables: *y*, *x*<sub>1</sub>, *x*<sub>2</sub>. In this study, we assumed that the parameter *z* was linearly related to *y*, and the value of c was 0.05 in the bifurcation analysis. For different values of  $\beta$ , we could solve the fixed points of *y*, and further solve the fixed points of *x*<sub>1</sub> and *x*<sub>2</sub> with individual fixed *y*.

#### Microfluidic chip design, fabrication and image acquisition

Microfluidic chip design: A new microfluidic chip was designed to observe the

induction dynamics of the ITS after adding IPTG (Fig. S7). There are six units in the microfluidic chip and each unit has three parallel main channels (100  $\mu$ m wide, 15  $\mu$ m high) so that the chip can be used to conduct experiments with six different experimental conditions or four different strain constructs simultaneously. Each unit comprises 1 inlet, 1 outlet, three main channels and 240 chambers. We also designed fences in the inlets and outlets to prevent Polydimethylsiloxane (PDMS) debris from blocking the channels. An array of cell culture chambers is connected to each side of the main channel. The height of the cell growth chambers (approximately 1.3  $\mu$ m) was slightly higher than the height of an *E. coli* cell, so that the loaded *E. coli* colonies in the chambers would be recorded at the single cell level (2D). The cell culture chamber consists of three parts: a rectangular part (50  $\mu$ m long, 25  $\mu$ m wide) is the main growth area, a triangular part is a transition region and a small rectangular part (7  $\mu$ m long, 1.5  $\mu$ m wide) is akin to a "mother machine"<sup>1</sup>.

Microfluidic device fabrication: The master mold for the device was fabricated in two layers (the first layer for the growth channels and the second layer for the main channels) by ultraviolet photolithography using standard methods. For each layer, SU-8 photoresist (Clariant Corp, Switzerland) was applied to a silicon wafer (Entegris, USA) by spin coating to appropriate thickness (corresponding to the channel height), after which patterns were created by exposing the uncured photoresist to ultraviolet light through custom quartz-chrome photomasks (Macrochem, USA). Microfluidic devices were fabricated by molding channel features into a polydimethylsiloxane (PDMS; RTV615, USA) slab and then bonding that slab to a glass coverslip. To produce the slab, dimethyl siloxane monomer (Sylgard 184, MOMENTIVE, USA) was mixed at an 8:1 ratio with curing agent (MOMENTIVE, USA), poured onto the silicon wafer master, degassed under vacuum, and cured at 65°C overnight after it was bubble-free. Holes to connect the main channels to the chambers used for medium perfusion were introduced using a hole puncher (Harris, USA), and individual chips were cut and bonded onto water-cleaned cover slips using oxygen plasma treatment on a plasma cleaner (Harrick Plasma, USA). The bonded chips were baked at 65°C overnight before use.

**Microscopy and automated image acquisition:** The microfluidics device was mounted onto a Nikon Eclipse Ti (Nikon, Japan) inverted microscope equipped with a  $40 \times Plan$  Apo objective or  $60 \times Plan$  Apo oil objective (NA 1.4, Nikon). To implement the real-time observation of the behavior of *E. coli*, we set up an auto-cultivation and observation system on the described Nikon Ti-E microscope. Images of the *E. coli* cells in the chambers were acquired under the control of NIS-Elements AR software (Nikon, Japan). The microscope scanned a series of pre-set points every 10 min, using a programmable motorized x–y stage and a PFS (perfect focus system) focus-maintaining unit. With the combination of the solution injection system and the imaging system, we were able to record the growth history of different individual bacteria at the single-cell level when these cells were exposed to LB culture medium. The temperature of the microfluidic chip was maintained at 37°C throughout the experiment using the microscope's temperature-control system. Images were acquired every 10 min and saved as 16-bit TIFF files.

Part	Туре	DNA sequence
<b>P</b> <sub>T7</sub>	promoter	taatacgactcactata
<b>P</b> <sub>T7M4</sub>	promoter	tataacgactcactata
HKcI O	operator	tgaaccataagttca
cI 0	operator	acctctggcggtgata
T7RNAP RBS	RBS	ggatccccaccagtatcgcgttaccccggg
HKcl RBS	RBS	ctacctaggtaattagaagcaacccggaggtaccagtcgac
cI RBS	RBS	actaggatccagacaaggcacccatcttcaggaggtcccggg
B0034	RBS	agaaagaggagaaa
SfGFP RBS	RBS	actagagaaagaggagaaatactag
(pITS)		

#### Table S1. Sequences of genetic parts

mRFP1 RBS	RBS	ccgagtgcaggggggggaatctgat
(pITS)		
HKcI	ORF	atggttcaacagaaagagcgtgaaactttctcgcagaggcttgcgctggcctgtgataaagcgg
		${\it gattacctttgcatggtaggcaggctgatttagctgtcaggcttaaggtcacaccaaaagccatt}$
		agtaa atggtt caacggggagt caataccaagaa aagacaagatggaat ctctggctt cggtg
		ctgggaactactgctgcatatctgcatggctatgctgatgatgacggtatcacggtaaatcatct
		atcaagatcaaatgattattatcgtgttgatgtattggatgttcaggcgagcgccgggccaggaa
		ccatggtttccaatgaatttatagaaaagataagagcaattgaatatacgaccgagcaggcaa
		${\tt gaattttatttaatggaaggccacaggaaagcgtaaaagtcatcacggttcgcggtgacagcat$
		${f g}{f g}{f g}{f g}{f g}{f g}{f g}{f g}{f a}{f c}{f a}{f c}{f c}{f a}{f c}{f g}{f a}{f g}{f g}{f g}{f g}{f g}{f g}{f a}{f g}{f a}{f c}{f a}{f a}{f c}{f a}{f a}{f c}{f a}{f a}{f c}{f a}{f a}{f a}{f a}{f a}{f c}{f a}{f a}{h a}{f a}{f a}{f a}{f a}{f a}{h $
		atggcatttatgtgtttgtatacgggaaaacaatgcacgttaagcgcctgcaaatgcaaaagaa
		${\it caggcttgccgtcatctctgacaatgccgcttatgatcgatggtacatagaagaaggtgaagaa$
		${\it gag}$ caacttcacattctagccaaagtcctcattaggcagtcaatcgattacaagcgattcgga
cI	ORF	atgagcacaaaaaagaaaccattaacacaagagcagcttgaggacgcacgtcgccttaaagc
		aatttatgaaaaaaagaaaaatgaacttggcttatcccaggaatctgtcgcagacaagatggg
		gatggggcagtcaggcgttggtgctttatttaatggcatcaatgcattaaatgcttataacgccg
		cattgettgeaaaaatteteaaagttagegttgaagaatttageeetteaategeeagaaaate
		tacgagatgtatgaagcggttagtatgcagccgtcacttagaagtgagtatgagtaccctgttttt
		tctcatgttcaggcagggatgttctcacctgagcttagaacctttaccaaaggtgatgcggagag
		atgggtaagcacaaccaaaaaagccagtgattctgcattctggcttgaggttgaaggtaattcc
		atgaccgcaccaacaggctccaagccaagctttcctgacggaatgttaattctcgttgaccctga
		gcaggctgttgagccaggtgatttctgcatagccagacttgggggtgatgagtttaccttcaaga
		aactgatcagggatagcggtcaggtgtttttacaaccactaaacccacagtacccaatgatccc
		atgcaatgagagttgttccgttgtggggaaagttatcgctagtcagtggcctgaagagacgtttg
		gctga
SfGFP	ORF	atgcgtaaaggcgaagagctgttcactggtgtcgtccctattctggtggaactggatggtgatgt
		caacggtcataagttttccgtgcgtggcgagggtgaaggtgacgcaactaatggtaaactgac
		getgaagtteatetgtaetaetggtaaaetgeeggtaeettggeegaetetggtaaegaegetga
		cttatggtgttcagtgctttgctcgttatccggaccatatgaagcagcatgacttcttcaagtccgc

mRFP1		ORF	atggcttcctccgaagacgttatcaaagagttcatgcgtttcaaagttcgtatggaaggttccgtt
			agcggtcacgagttcgaaatcgaaggtgaaggtgaaggtcgtccgtacgaaggtacccagac
			cgctaaactgaaagttaccaaaggtggtccgctgccgttcgcttgggacatcctgtccccgcagt
			tccagtacggttccaaagettacgttaaacacceggetgacateeeggactacetgaaactgtee
			tt cccggaaggtt tcaaatgggaacgtgt tatgaactt cgaagacggtggtgttgt taccgt tac
			ccaggactcctccctgcaagacggtgagttcatctacaaagttaaactgcgtggtaccaacttcc
			cgtccgacggtccggttatgcagaaaaaaaccatgggttgggaagcttccaccgaacgtatgt
			acccggaagacggtgctctgaaaggtgaaatcaaaatgcgtctgaaactgaaagacggtggt
			cactacgacgetgaagttaaaaccacctacatggetaaaaaaccggttcagetgecgggtgett
			acaaaaccgacatcaaactggacatcacctcccacaacgaagactacaccatcgttgaacagt
			acgaacgtgctgaaggtcgtcactccaccggtgcttaa
Double	<b>T7</b>	terminator	ccaggcatcaaataaaacgaaaggctcagtcgaaagactgggcctttcgttttatctgttgtttgt
terminator			cggtgaacgctctctactagagtcacactggctcaccttcgggtgggcctttctgcgtttatatact
			agagetgetaacaaageeegaaaggaagetgagttggetgetgeegeegetgageaataacta
			gcataaccccttggggcctctaaacgggtcttgaggggttttttgctgaaaggaggaactatatc
			cggattactagaggtcatgcttgccatctgttttcttgcaagat
RiboJ <sup>2</sup>		insulator	agctgtcaccggatgtgctttccggtctgatgagtccgtgaggacgaaacagcctctacaaata
			attttgtttaa

# Supplemental references

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